TMAG5123 同一面内、高精度、高電圧、ホール・エフェクト・スイッチ

1 特長

- 同一面内、オムニポーラ・ホール・エフェクト・スイッチ
- 高い磁気感度:
  - TMAG5123B:±4.1mT (標準値)
  - TMAG5123C:±7.5mT (標準値)
  - TMAG5123D:±10.9mT (標準値)
- 広い電圧範囲に対応
  - 2.5V～38V の V_{CC} 範囲で動作
  - 外部レギュレータ不要
- 広い動作温度範囲
  - 動作時周囲温度範囲:-40℃～+125℃
- 30kHz の連続変換
- オープン・ドレイン出力
- SOT-23 パッケージ・オプション
- 保護機能
  - 最大 40V の負荷ダンプをサポート
  - -20V までのバッテリ逆極性保護
  - 出力短絡保護
  - 出力電流制限

2 アプリケーション

- 大型家電製品
- 小型家電製品
- コードレス掃除ロボット
- 流量計
- 住宅用ブレーカ
- 開放および短絡の検出

3 概要

TMAG5123 はチョッパ安定化されたオムニポーラ、アクティブ LOW 、同一平面内、ホール・エフェクト・スイッチ・センサです。TMAG5123 は表面実装の SOT-23 パッケージであり、プリント基板 (PCB) の表面に平行な磁界を測定するので、センサの機械的配置が容易になります。

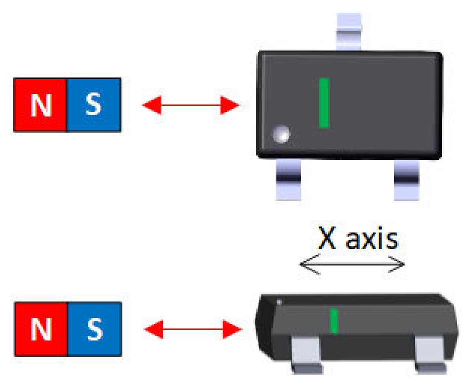
アプリケーション固有の要件に合わせて、異なる感度レベルの製品が提供されています。印加された磁束密度の値が磁界の絶対値で動作点 (BOP) スレッショルドを上回ると、オープン・ドレイン出力は LOW 状態の電圧になります。この出力は、印加された磁界の絶対値が復帰点 (BRP) スレッショルドよりも低くなるまで LOW のままです。

TMAG5123 は、2.5V～38V の広い動作電圧範囲と、最大 -20V の逆極性保護を内蔵しているため、産業用アプリケーションに適した堅牢な動作を実現できます。

製品情報

部品番号	パッケージ(1)	本体サイズ (公称)
TMAG5123	SOT-23 (3)	2.92mm × 1.30mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。



同一平面内センサ

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4 Revision History

DATE	REVISION	NOTES
May 2021	*	Initial Release

5 Device Comparison Table

DEVICE	DEVICE OPTION	Threshold level (BOP)
TMAG5123	B	4.1mT
	C	7.5mT
	D	10.9mT

6 Pin Configuration and Functions

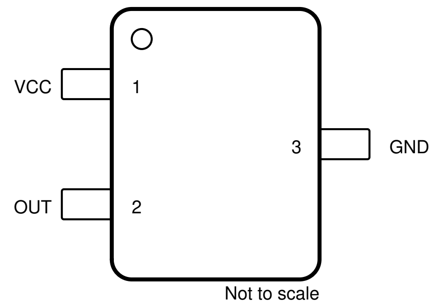

図 6-1. DBZ Package 3-Pin SOT-23 Top View

表 6-1. Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	VCC	Power supply	2.5-V to 38-V power supply. Connect a ceramic capacitor with a value of at least 0.01 µF (minimum) between VCC and ground.
2	OUT	Output	Hall sensor open-drain output. The open drain requires a pull-up resistor
3	GND	Ground	Ground reference.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[(1)]

		MIN	MAX	UNIT
Power Supply Voltage	V_{CC}	–20	40	V
Magnetic Flux Density,BMAX		Unlimited		T
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, allpins[(1)]	±2000	V
		Charged device model (CDM), per JEDEC specificationJESD22-C101, all pins[(2)]	± 500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Power supply voltage	2.5	38	V
V_O	Output pin voltage	0	38	V
I_{SINK}	Output pin current sink	0	20	mA
T_A	Ambient temperature	–40	125	°C

7.4 Thermal Information

THERMAL METRIC[(1)]		TMAG5123 DBZ (SOT-23) 3 PINS	UNIT
$R_{θJA}$	Junction-to-ambient thermal resistance	197.7	°C/W
$R_{θJC(top)}$	Junction-to-case (top) thermal resistance	87.1	°C/W
$R_{θJB}$	Junction-to-board thermal resistance	27.4	°C/W
$Ψ_{JT}$	Junction-to-top characterization parameter	3.7	°C/W
$Ψ_{JB}$	Junction-to-board characterization parameter	27.1	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
I_{CC}	Operating supply current	VCC = 2.5V to 38V, T_A = 25°C		3.5		mA
I_{CC}	Operating supply current	VCC = 2.5V to 38V, T_A = – 40°C to 125°C		3.5	5.4	mA
I_{RCC}	Reverse-battery current	VCC = -20V	-100			µA
t_{ON}	Power-on-time			62.5		µs
P_{OS}	Power-on-state	V_{CC}>V_{CCmin}, t>=t_{ON}		High		
OUTPUT						
V_{OL}	Low-level output voltage	I_{OL}=5mA	0		0.5	V
I_{OH}	Output leakage current	V_{CC}=5V		0.1	1	µA
I_{SC}	Output short-circuit current			65	100	mA
t_R	Output rise time	RL=1kΩ, CL=50pF, VCC = 12 V		0.2		µs
t_F	Output fall time	RL=1kΩ, CL=50pF, VCC = 12 V		0.2		µs
t_{PD}	Propagation delay time	Change in B field to change in output		50		µs
FREQUENCY RESPONSE						
f_{CHOP}	Chopping frequency			320		kHz
f_{BW}	Signal bandwidth			10		kHz

7.6 Magnetic Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
TMAG5123B						
B_{OP}	Magnetic field operating point	VCC = 2.5V to 38V, T_A = – 40°C to 125°C	±2.2	±4.1	±6	mT
B_{RP}	Magnetic field release point		±0.3	±2.2	±4	mT
B_{HYS}	Magnetic hysteresis B_{OP} - B_{RP}		±0.5	±1.9	±3	mT
TMAG5123C						
B_{OP}	Magnetic field operating point	VCC = 2.5V to 38V, T_A = – 40°C to 125°C	±5.5	±7.5	±9.5	mT
B_{RP}	Magnetic field release point		±3.5	±5.5	±7.5	mT
B_{HYS}	Magnetic hysteresis B_{OP} - B_{RP}		±0.5	±2	±3	mT
TMAG5123D						
B_{OP}	Magnetic field operating point	VCC = 2.5V to 38V, T_A = – 40°C to 125°C	±8.7	±10.9	±13	mT
B_{RP}	Magnetic field release point		±6.7	±8.9	±11	mT
B_{HYS}	Magnetic hysteresis B_{OP} - B_{RP}		±0.5	±2	±3	mT

7.7 Typical Characteristics

at T_A = 25 °C typical and V_{CC} = 6V (unless otherwise noted)

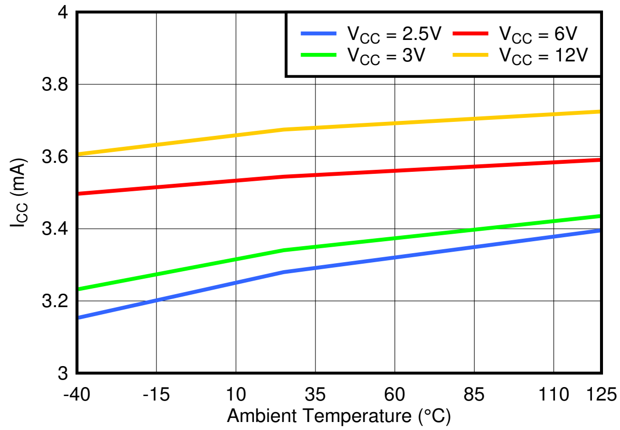

図 7-1. TMAG5123 I_{CC} vs Temperature

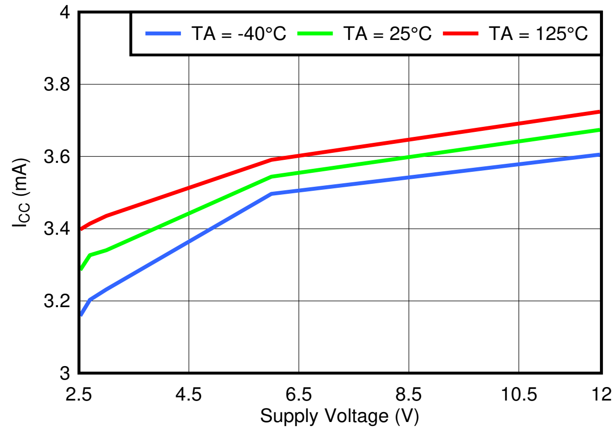

図 7-2. TMAG5123 I_{CC} vs Voltage

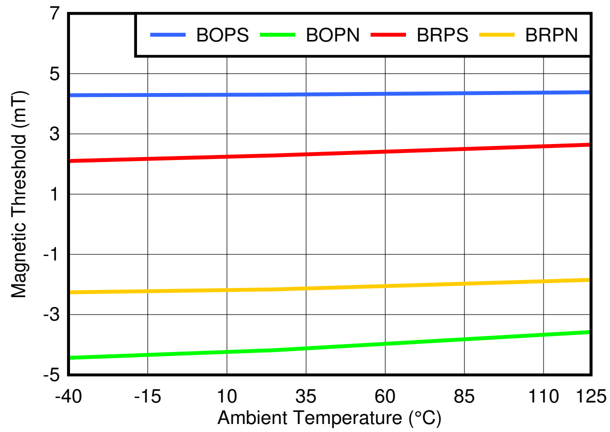

図 7-3. TMAG5123B Magnetic Thresholds vs Temperature

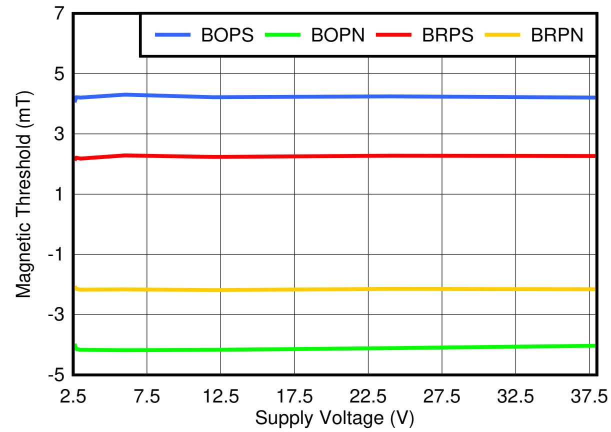

図 7-4. TMAG5123B Magnetic Thresholds vs Voltage

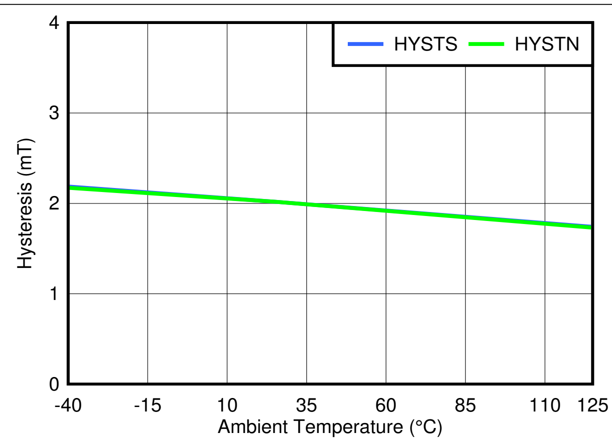

図 7-5. TMAG5123B Hysteresis vs Temperature

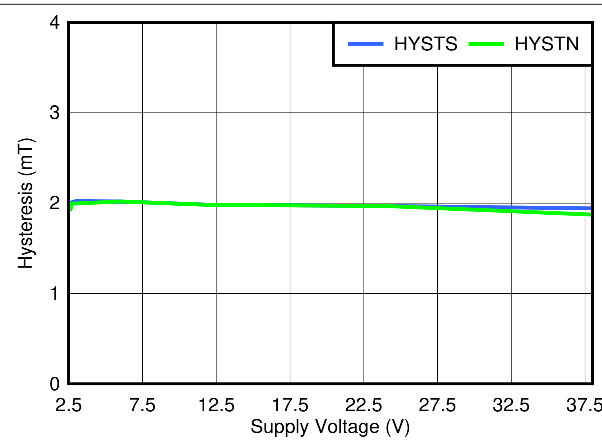

図 7-6. TMAG5123B Hysteresis vs Supply Voltage

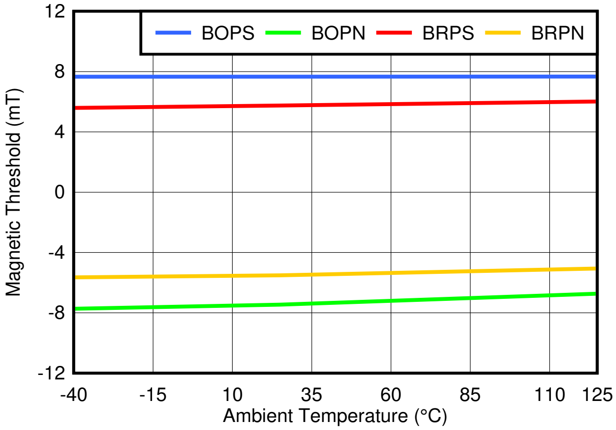

図 7-7. TMAG5123C Magnetic Thresholds vs Temperature

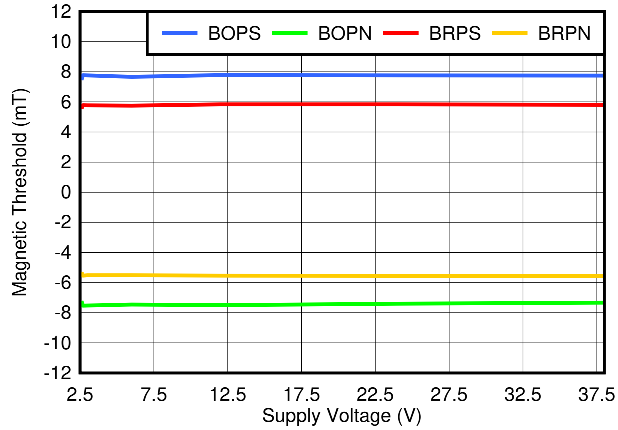

図 7-8. TMAG5123C Magnetic Thresholds vs Voltage

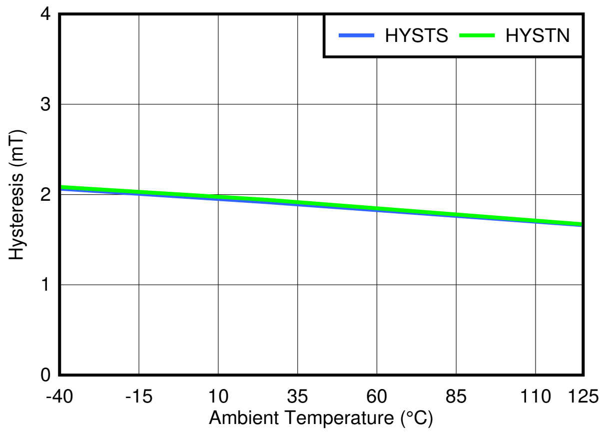

図 7-9. TMAG5123C Hysteresis vs Temperature

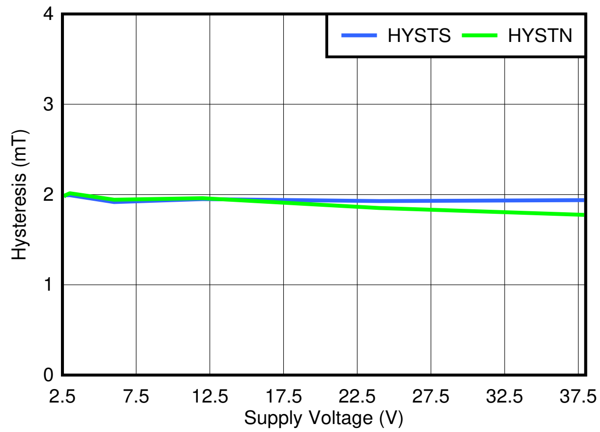

図 7-10. TMAG5123C Hysteresis vs Supply Voltage

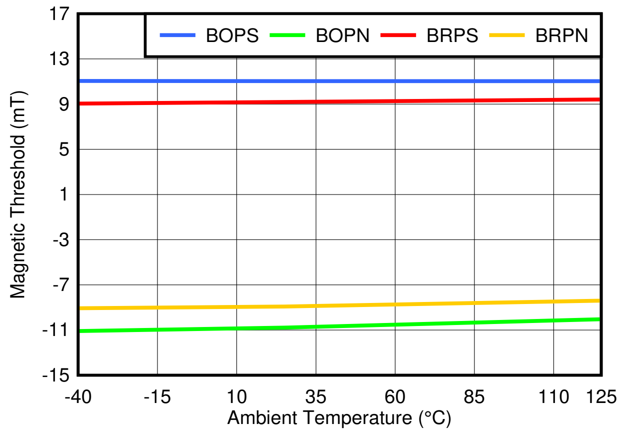

図 7-11. TMAG5123D Magnetic Thresholds vs Temperature

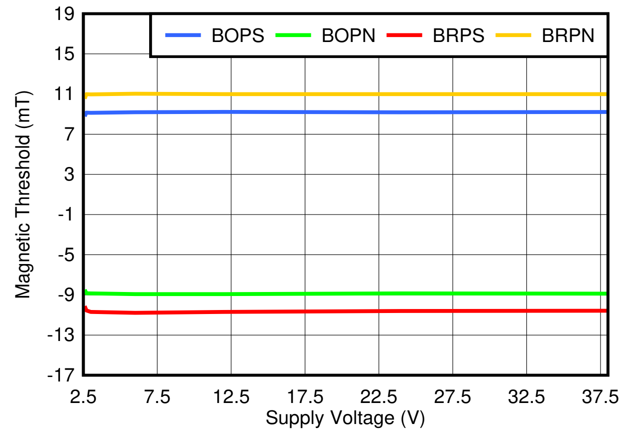

図 7-12. TMAG5123D Magnetic Thresholds vs Voltage

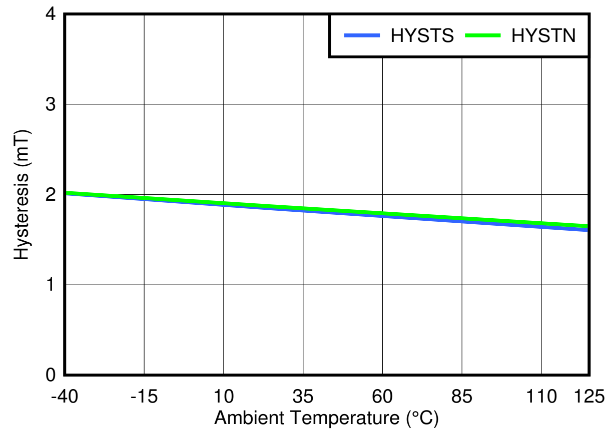

図 7-13. TMAG5123D Hysteresis vs Temperature

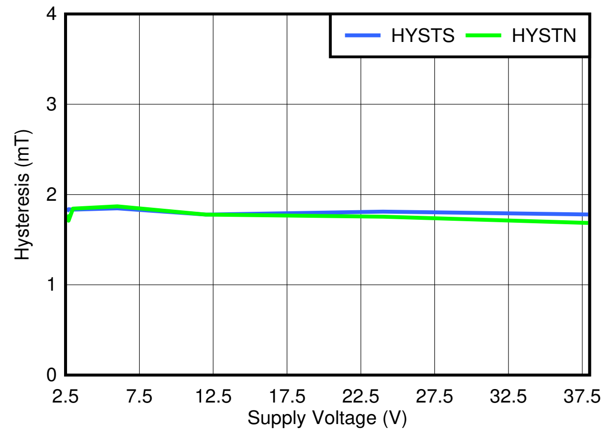

図 7-14. TMAG5123D Hysteresis vs Supply Voltage

8 Detailed Description

8.1 Overview

The TMAG5123 device is a chopper-stabilized Hall sensor with a digital omnipolar switch output for magnetic sensing applications. The TMAG5123 device can be powered with a supply voltage range between 2.5-V and 38 V, and can withstand –20-V reverse battery conditions continuously. Note that the TMAG5123 device will not operate when approximately –20-V to 2.5-V is applied to the VCC pin (with respect to GND). In addition, the device can withstand voltages up to 40 V for transient durations.

While most of the Hall-effect sensors switch their output in the presence of a vertical field, the TMAG5123 will switch the output in the presence of a horizontal field. The TMAG5123 is then an in-plane or vertical sensor, sensitive to a horizontal or parallel magnetic fields.

The omnipolar configuration allows the Hall sensor to respond to either a south or north pole. A strong magnetic field of either polarity will cause the output to pull low (operate point, BOP), and a weaker magnetic field will cause the output to release (release point, BRP). Hysteresis is included in between the operate and release points, so magnetic field noise will not trip the output accidentally.

An external pullup resistor is required on the OUT pin. The OUT pin can be pulled up to VCC, or to a different voltage supply. This allows for easier interfacing with controller circuits.

8.2 Functional Block Diagram

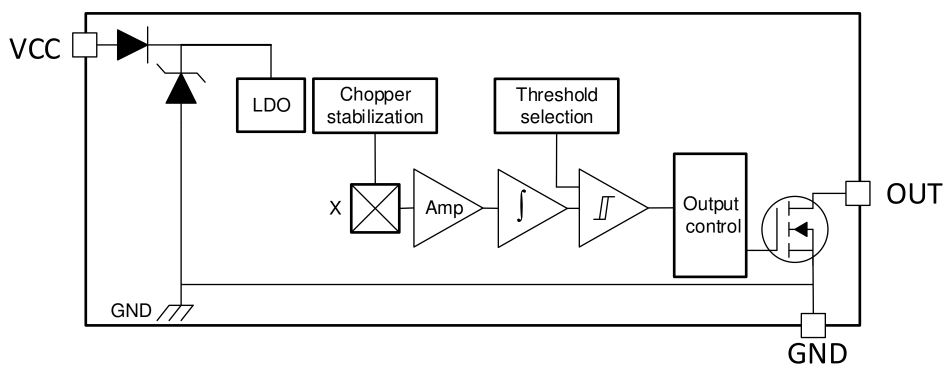

図 8-1. Block Diagram

8.3 Feature Description

8.3.1 Field Direction Definition

The TMAG5123 is sensitive to both south and north poles in the same plane as the die as shown 図 8-2.

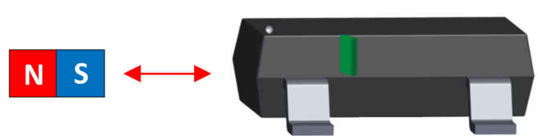

図 8-2. Field Direction Definition

8.3.2 Device Output

The TMAG5123 is featured with an open drain output. In order to generate a two state output, a pull-up resistor needs to be added.

Once the device is powered and with no magnetic field applied to it, the output stays at Vout(H). As an omnipolar sensor the output will go down to Vout(L) when the field increase beyond the BOP threshold either with a north or a south magnetic field. When the field decrease below the BRP threshold, either with a north or a south magnetic field, the output will go up to Vout(H)

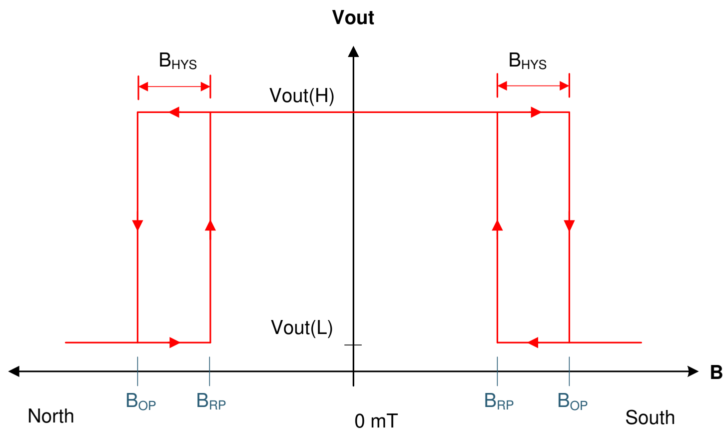

図 8-3. Omnipolar Functionality

8.3.3 Protection Circuits

The TMAG5123 device is protected against load dump and reverse-supply conditions

8.3.3.1 Load Dump Protection

The TMAG5123 device operates at DC VCC conditions up to 38-V nominally, and can additionally withstand VCC = 40-V. No current-limiting series resistor is required for this protection.

8.3.3.2 Reverse Supply Protection

The TMAG5123 device is protected in the event that the VCC pin and the GND pin are reversed (up to –20-V).

8.3.4 Hall Element Location

The sensing element inside the device is in the center of both packages when viewed from the top. 図 8-4 shows the tolerances and side-view dimensions.

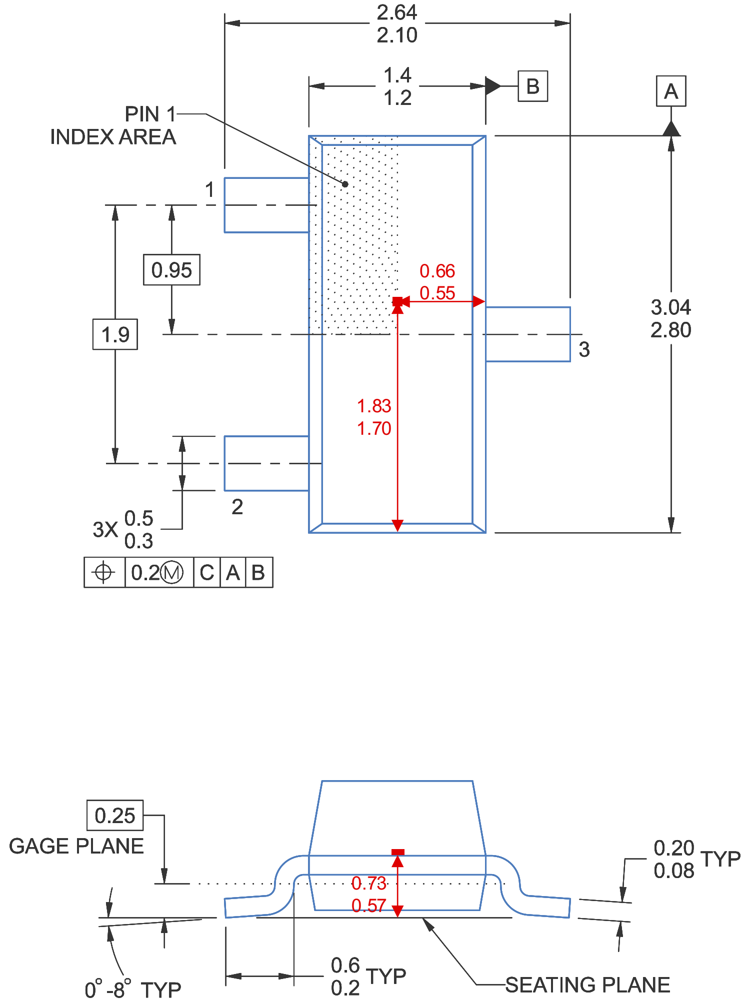

図 8-4. Hall Element Location

8.3.5 Power-On Time

図 8-5 shows the behavior of the device after the V_{CC} voltage is applied and when the field is below the B_{OP} threshold. Once the minimum value for V_{CC} is reached, the TMAG5123 will take time t_{ON} to power up and then time t_{PD} to update the output to a level High.

図 8-6 shows the behavior of the device after the V_{CC} voltage is applied and when the field is above the B_{OP} threshold. Once the minimum value for V_{CC} is reached, the TMAG5123 will take time t_{ON} to power up and then time t_{PD} to update the output to a level Low.

The output value during t_{ON} is unknown in both cases. The output value at the end of t_{ON} will be set at High.

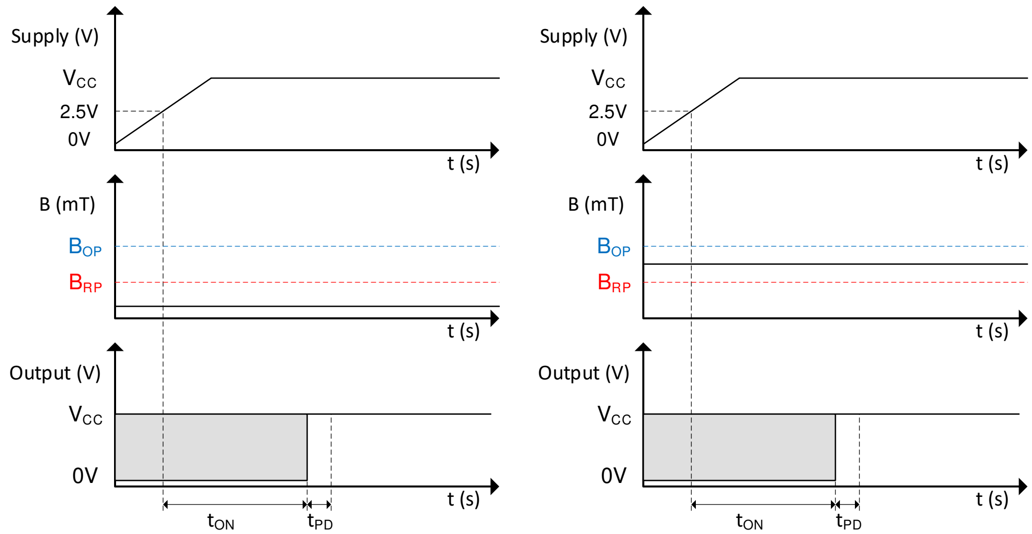

図 8-5. Power-On Time When B < B_{OP}

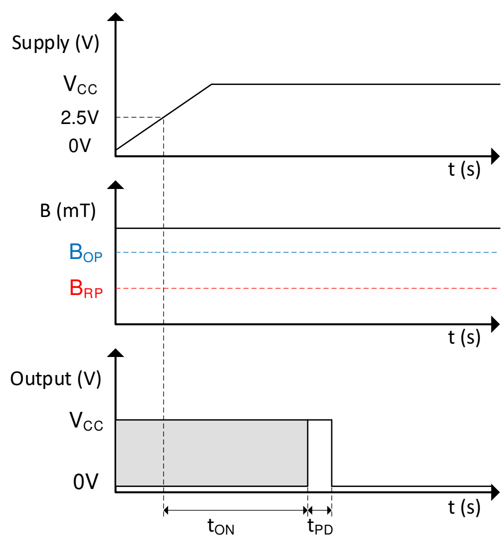

図 8-6. Power-On Time When B > B_{OP}

8.3.6 Propagation Delay

The TMAG5123 samples the Hall element at a nominal sampling interval of t_{PD} to detect the presence of a magnetic south or north pole. Between each sampling interval, the device calculates the average magnetic field applied to the device. If this average value crosses the B_{OP} or B_{RP} threshold, the device changes the corresponding level as defined in 図 8-3. The Hall sensor + magnet system is by nature asynchronous, therefore the propagation delay (t_{PD}) will vary depending on when the magnetic field goes above the B_{OP} value. As shown in 図 8-7, the output delay also depends on when the magnetic field goes above the B_{OP} value.

The first graph in 図 8-7 shows the typical case. The magnetic field goes above the B_{OP} value at the moment the output is updated. The part will only require one sampling period of t_{PD} to update the output.

The second graph in 図 8-7 shows a magnetic field going above the B_{OP} value just before half of the sampling period. This is the best-case scenario where the output is updated in just half of the sampling period.

Finally, the third graph in 図 8-7 shows the worst-case scenario where the magnetic field goes above the B_{OP} value just after half of the sampling period. At the next output update, the device will still see the magnetic field under the B_{OP} threshold and will require a whole new sampling period to update the output.

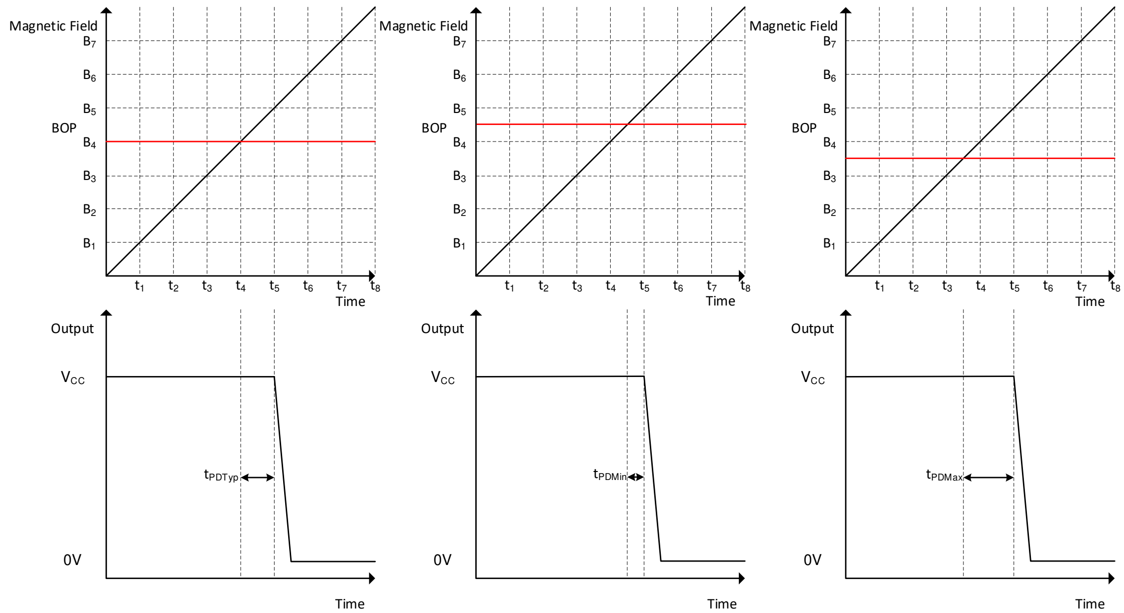

図 8-7. Field Sampling Timing

図 8-8 shows TMAG5123 propagation delay analysis when a magnetic south or north pole is applied. The Hall element of the TMAG5123 experiences an increasing magnetic field as a magnetic south or north pole approaches the device, as well as a decreasing magnetic field as a magnetic south or north pole moves away. At time t_1, the magnetic field goes above the B_{OP} threshold. The output will then start to move after the propagation delay (t_{PD}). This time will vary depending on when the sampling period is, as shown in 図 8-7. At t_2, the output start pulling the output voltage Low. At t_3, the output is completely pulled down. The same process happens on the other way when the magnetic value is going under the B_{RP} threshold.

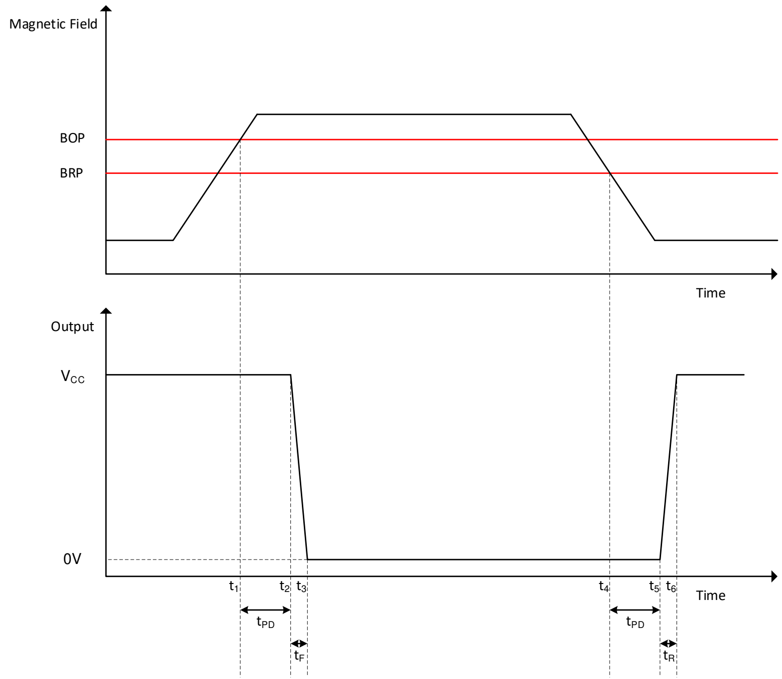

図 8-8. Propagation Delay

8.3.7 Chopper Stabilization

The Basic Hall-effect sensor consists of four terminals where a current is injected through two opposite terminals and a voltage is measured through the other opposite terminals. The voltage measured is proportional to the current injected and the magnetic field measured. By knowing the current inject, the device can then know the magnetic field strength. The problem is that the voltage generated is small in amplitude while the offset voltage generated is more significant. To create a precise sensor, the offset voltage must be minimized.

Chopper stabilization is one way to significantly minimize this offset. It is achieved by "spinning" the sensor and sequentially applying the bias current and measuring the voltage for each pair of terminals. This means that a measurement is completed once the spinning cycle is completed. The full cycle is completed after sixteen measurements. The output of the sensor is connected to an amplifier and an integrator that will accumulate and filter out a voltage proportional to the magnetic field present. Finally, a comparator will switch the output if the voltage reaches either the BOP or BRP threshold (depending on which state the output voltage was previously in).

The frequency of each individual measurement is referred as the Chopping frequency, or f_{CHOP}. The total conversion time is referred as the Propagation delay time, t_{PD}, and is basically equal to $16/f_{CHOP}$. Finally, the Signal bandwidth, f_{BW}, represents the maximum value of the magnetic field frequency, and is equal to $(f_{CHOP}/16)/2$ as defined by the sampling theorem.

8.4 Device Functional Modes

The device operates in only one mode when operated within the *Recommended Operating Conditions*.

9 Application and Implementation

Note

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

The TMAG5123 is typically used in magnetic-field sensing applications to detect the proximity of a magnet that is in the "in-plane" axis from the sensor. The magnet is often attached to a movable component in the system.

The TMAG5123 is a Hall sensor that implements a Hall sensing element that senses parallel to the package of the part rather than through the z-axis of the device. This eases constraints in system design where a parallel magnetic field is needed to be detected, but normal industry packages, such as TO-92 are undesirable due to space constraints.

9.2 Typical Applications

9.2.1 In-Plane Typical Application Diagrams

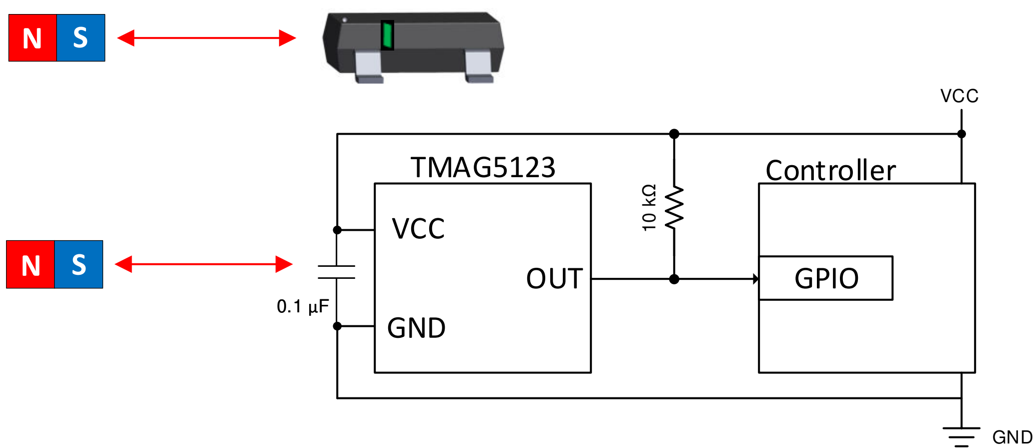

図 9-1. Typical In-Plane Sensing Diagram

9.2.1.1 Design Requirements

For this design example, use the parameters listed in one of the 3 tables below depending on wich version of the device is used.

表 9-1. Design Parameters for TMAG5123B

DESIGN PARAMETER	EXAMPLE VALUE
Vcc	12V
TMAG5123 Device	TMAG5123B
Magnet	1-cm Cube NdFeB (N45)
Minimum Magnet Distance to Operate	2.8 cm (±6mT) with BOP Max
Maximum Magnet Distance to Release	8.4 cm (±0.3mT) with BRP Min

表 9-2. Design Parameters for TMAG5123C

DESIGN PARAMETER	EXAMPLE VALUE
Vcc	12V
TMAG5123 Device	TMAG5123C
Magnet	1-cm Cube NdFeB (N45)
Minimum Magnet Distance to Operate	2.33 cm (±9.5mT) with BOP Max
Maximum Magnet Distance to Release	3.44 cm (±3.5mT) with BRP Min

表 9-3. Design Parameters for TMAG5123D

DESIGN PARAMETER	EXAMPLE VALUE
Vcc	12V
TMAG5123 Device	TMAG5123D
Magnet	1-cm Cube NdFeB (N45)
Minimum Magnet Distance to Operate	2.04 cm (±13mT) with BOP Max
Maximum Magnet Distance to Release	2.68 cm (±6.7mT) with BRP Min

9.2.1.2 Detailed Design Procedure

When designing a digital-switch magnetic sensing system, three variables should always be considered: the magnet, sensing distance, and threshold of the sensor.

The TMAG5123 device has a detection threshold specified by parameter B_{OP}, which is the amount of magnetic flux required to pass through the Hall sensor mounted inside the TMAG5123. To reliably activate the sensor, the magnet must apply a flux greater than the maximum specified B_{OP}. In such a system, the sensor typically detects the magnet before it has moved to the closest position, but designing to the maximum parameter ensures robust turn-on for all possible values of B_{OP}. When the magnet moves away from the sensor, it must apply less than the minimum specified B_{RP} to reliably release the sensor.

Magnets are made from various ferromagnetic materials that have tradeoffs in cost, drift with temperature, absolute maximum temperature ratings, remanence or residual induction (B_r), and coercivity (H_c). The B_r and the dimensions of a magnet determine the magnetic flux density (B) it produces in 3-dimensional space. For simple magnet shapes, such as rectangular blocks and cylinders, there are simple equations that solve B at a given distance centered with the magnet.

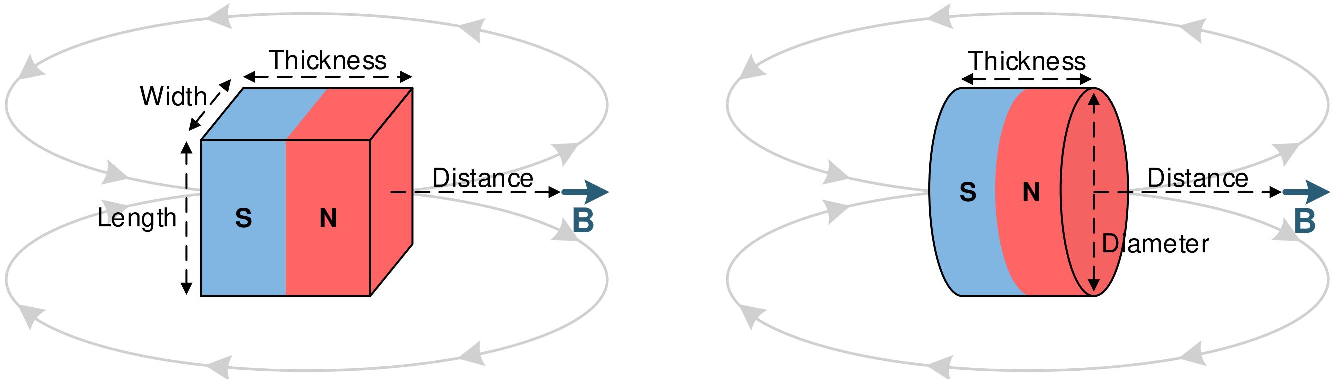

図 9-2. Rectangular Block and Cylinder Magnets

Use 式 1 for the rectangular block shown in 図 9-2:

$$\vec{B} = \frac{B_r}{\pi}\left(\arctan\left(\frac{WL}{2D\sqrt{4D^2 + W^2 + L^2}}\right) - \arctan\left(\frac{WL}{2(D+T)\sqrt{4(D+T)^2 + W^2 + L^2}}\right)\right) \tag{1}$$

Use 式 2 for the cylinder shown in 図 9-2:

$$\vec{B} = \frac{B_r}{2}\left(\frac{D+T}{\sqrt{(0.5C)^2 + (D+T)^2}} - \frac{D}{\sqrt{(0.5C)^2 + D^2}}\right) \tag{2}$$

where

- W is width.
- L is length.
- T is thickness (the direction of magnetization).
- D is distance.
- C is diameter.

An online tool, the *Hall Effect Switch Magnetic Field Calculator*, that uses these formulas is located at http://www.ti.com/product/tmag5123.

All magnetic materials generally have a lower B_r at higher temperatures. Systems should have margin to account for this, as well as for mechanical tolerances.

For the TMAG5123B, the maximum BOP is 4.5 mT. Choosing a 1-cm cube NdFeB N45 magnet, Equation 1 shows that this point occurs at 3.05 cm. This means that, provided the design places the magnet within 3.05 cm from the sensor during a "turn-on" event, the magnet will activate the sensor. The removal of the magnet away from the device will ensure a crossing of the minimum BRP point and will return the device to its initial state.

9.2.1.3 Application Curve

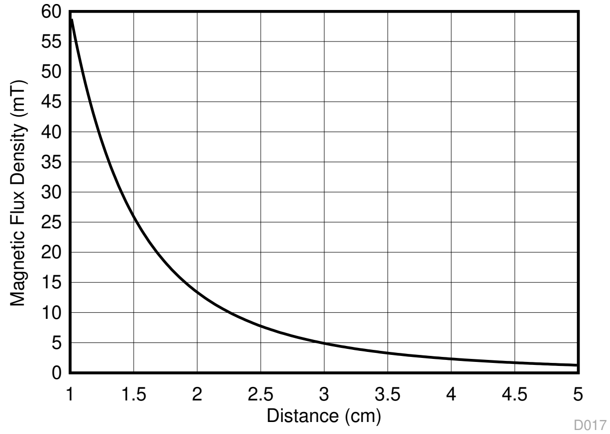

図 9-3. Magnetic Profile of a 1-cm Cube NdFeB Magnet

10 Power Supply Recommendations

The TMAG5123 is powered from 2.5-V to 38-V DC power supplies. A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.01 µF.

11 Layout

11.1 Layout Guidelines

The bypass capacitor should be placed near the TMAG5123 to reduce noise.

Generally, using PCB copper planes underneath the TMAG5123 device has no effect on magnetic flux, and does not interfere with device performance. This is because copper is not a ferromagnetic material. However, If nearby system components contain iron or nickel, they may redirect magnetic flux in unpredictable ways.

11.2 Layout Example

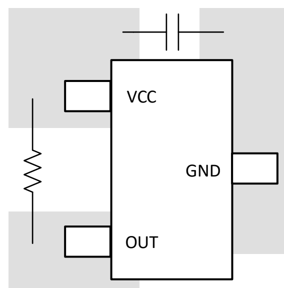

図 11-1. TMAG5123 Layout Example

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 サポート・リソース

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12.3 Trademarks

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12.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

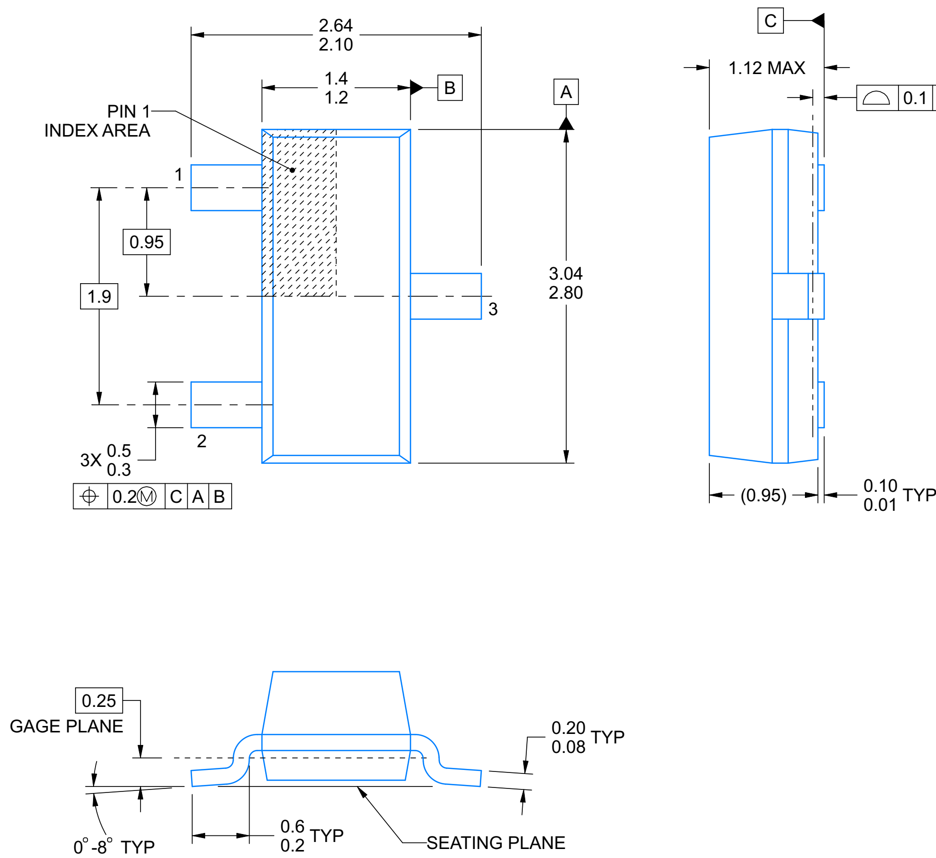
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGE OUTLINE

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



4214838/C 04/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.

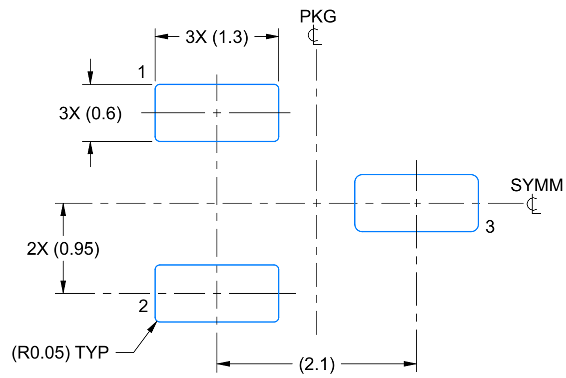
www.ti.com

EXAMPLE BOARD LAYOUT

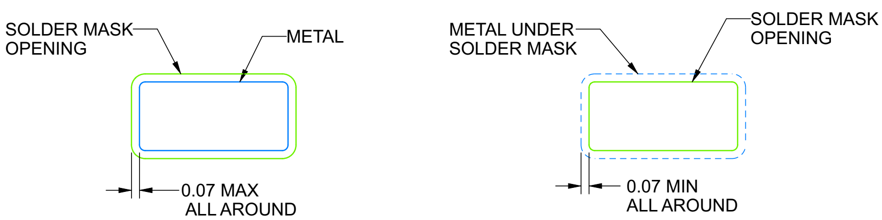
DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
SCALE:15X



NON SOLDER MASK DEFINED (PREFERRED)

SOLDER MASK DEFINED

SOLDER MASK DETAILS

4214838/C 04/2017

NOTES: (continued)

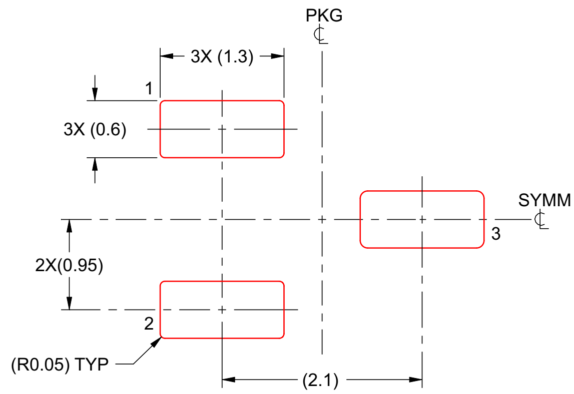
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/C 04/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

TEXAS INSTRUMENTS
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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TMAG5123B1CQDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23B1
TMAG5123B1CQDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23B1
TMAG5123C1CQDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23C1
TMAG5123C1CQDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23C1
TMAG5123C1CQDBZT	Obsolete	Production	SOT-23 (DBZ) | 3	-	-	Call TI	Call TI	-40 to 125	23C1
TMAG5123D1CQDBZR	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23D1
TMAG5123D1CQDBZR.A	Active	Production	SOT-23 (DBZ) | 3	3000 | LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	23D1
TMAG5123D1CQDBZT	Obsolete	Production	SOT-23 (DBZ) | 3	-	-	Call TI	Call TI	-40 to 125	23D1

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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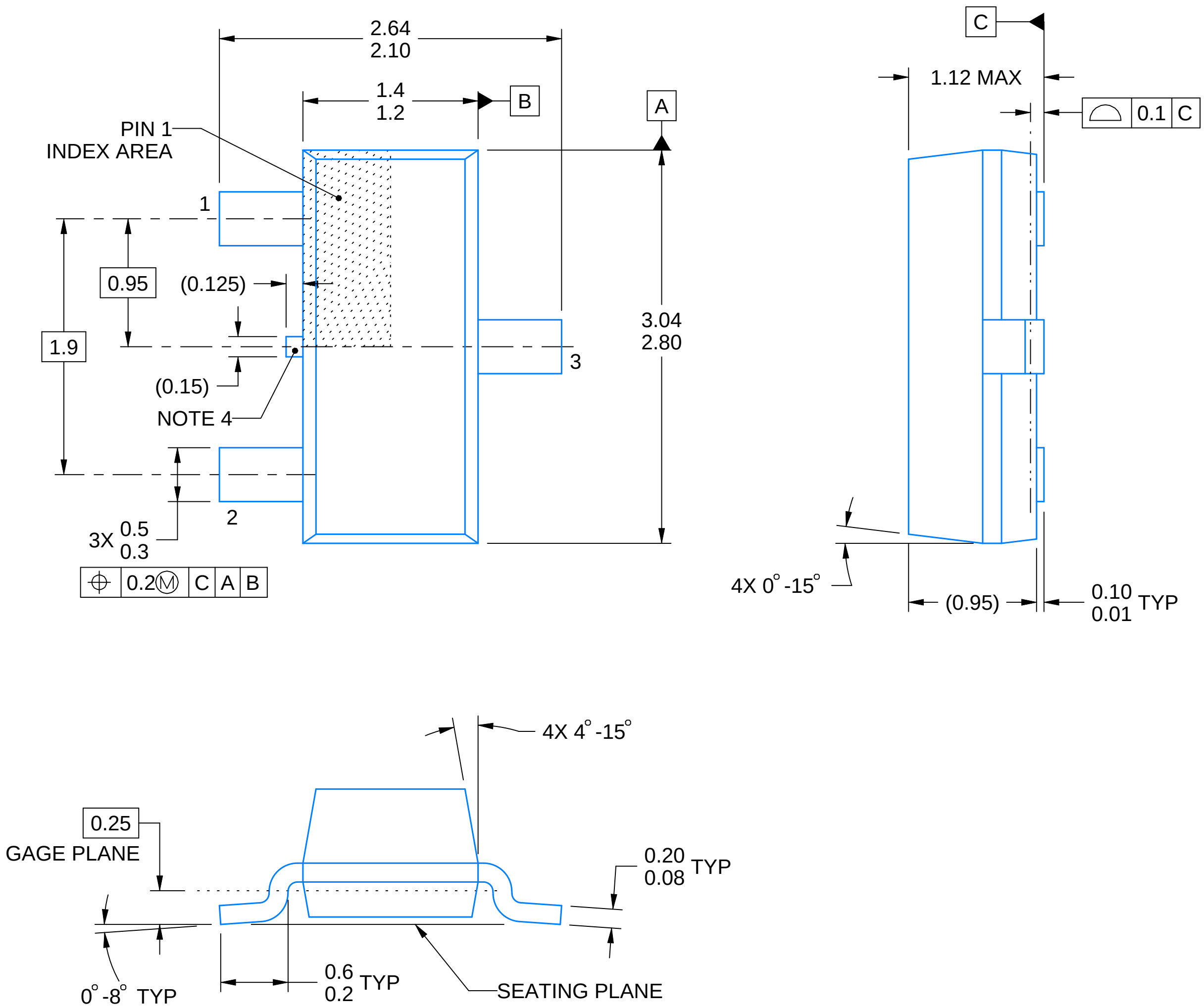
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TMAG5123 :

- Automotive : TMAG5123-Q1

NOTE: Qualified Version Definitions:

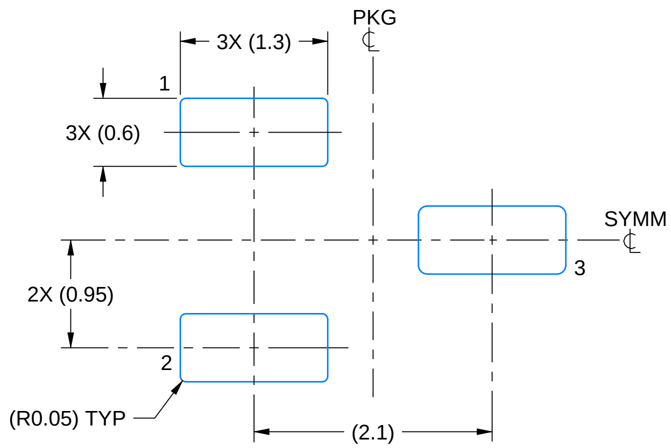
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



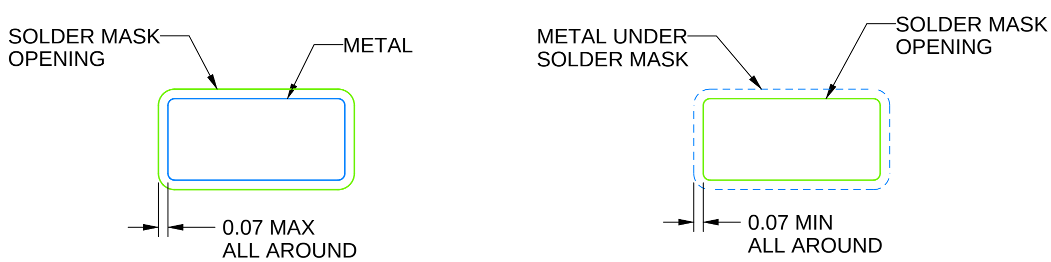
4214838/F 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



LAND PATTERN EXAMPLE
SCALE:15X



NON SOLDER MASK DEFINED (PREFERRED)

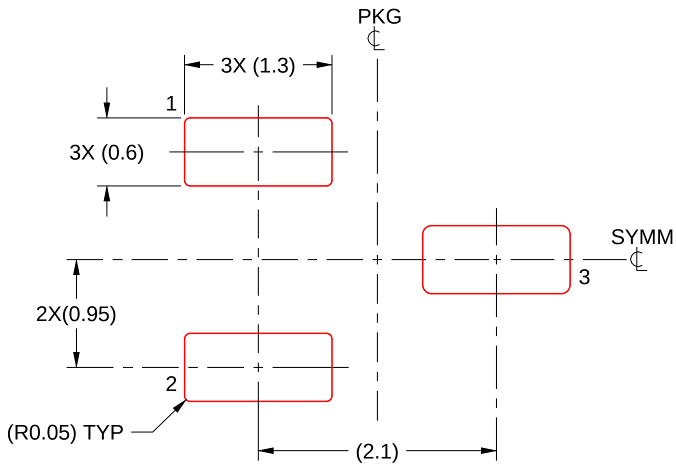
SOLDER MASK DEFINED

SOLDER MASK DETAILS

4214838/F 08/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/F 08/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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